

2N5038

NPN Silicon Transistors

Fast switching speeds and high current capacity ideally suit these parts for use in switching regulators, inverters, wide-band amplifiers and power oscillators in industrial and commercial applications.

Features

- High Speed - $t_f = 0.5 \mu\text{s}$ (Max)
- High Current - $I_{C(\text{max})} = 30$ Amps
- Low Saturation - $V_{CE(\text{sat})} = 2.5$ V (Max) @ $I_C = 20$ Amps
- Pb-Free Package is Available*

MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	90	Vdc
Collector-Base Voltage	V_{CBO}	150	Vdc
Collector-Emitter Voltage	V_{CEV}	150	Vdc
Emitter-Base Voltage	V_{EBO}	7	Vdc
Collector Current - Continuous	I_C	20	Adc
Collector Current - Peak (Note 2)	I_{CM}	30	
Base Current - Continuous	I_B	5	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	140 0.8	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.25	$^\circ\text{C/W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates JEDEC Registered Data.
2. Pulse Test: Pulse Width ≤ 10 ms, Duty Cycle $\leq 50\%$.

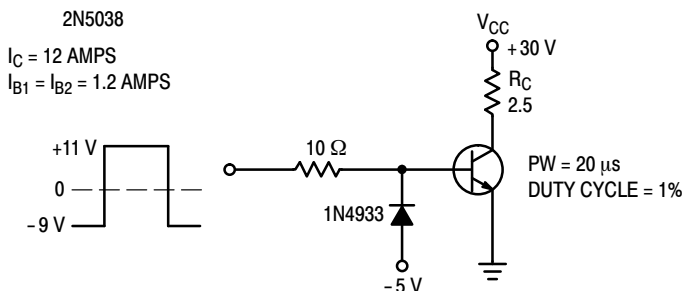


Figure 1. Switching Time Test Circuit

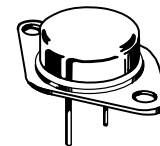
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



ON Semiconductor®

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**20 AMPERE
NPN SILICON
POWER TRANSISTORS
90 VOLTS - 140 WATTS**



TO-204AA (TO-3)
CASE 1-07
STYLE 1

MARKING DIAGRAMS



G = Pb-Free Package
A = Assembly Location
YY = Year
WW = Work Week
MEX = Country of Origin

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

2N5038

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted) (Note 3)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 4) ($I_C = 200\text{ mAdc}$, $I_B = 0$)	$V_{CEO(sus)}$	90	-	Vdc
Collector Cutoff Current ($V_{CE} = 140\text{ Vdc}$, $V_{BE(off)} = 1.5\text{ V}$) ($V_{CE} = 100\text{ Vdc}$, $V_{BE(off)} = 1.5\text{ Vdc}$, $T_C = 150^\circ\text{C}$)	I_{CEX}	-	50 10	mAdc
Emitter Cutoff Current ($V_{EB} = 5\text{ Vdc}$, $I_C = 0$) ($V_{EB} = 7\text{ Vdc}$, $I_C = 0$)	I_{EBO}	-	5 50	mAdc

ON CHARACTERISTICS (Note 4)

DC Current Gain ($I_C = 12\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$)	h_{FE}	20	100	-
Collector-Emitter Saturation Voltage ($I_C = 20\text{ Adc}$, $I_B = 5\text{ Adc}$)	$V_{CE(sat)}$	-	2.5	Vdc
Base-Emitter Saturation Voltage ($I_C = 20\text{ Adc}$, $I_B = 5\text{ Adc}$)	$V_{BE(sat)}$	-	3.3	Vdc

DYNAMIC CHARACTERISTICS

Magnitude of Common-Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio ($I_C = 2\text{ Adc}$, $V_{CE} = 10\text{ Vdc}$, $f = 5\text{ MHz}$)	$ h_{fe} $	12	-	-
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SWITCHING CHARACTERISTICS

RESISTIVE LOAD

Rise Time	$(V_{CC} = 30\text{ Vdc})$ $(I_C = 12\text{ Adc}, I_{B1} = I_{B2} = 1.2\text{ Adc})$	t_r	-	0.5	μs
Storage Time		t_s	-	1.5	μs

3. Indicates JEDEC Registered Data.

4. Pulse Test: Pulse Width $\leq 300\ \mu\text{s}$, Duty Cycle $\leq 2\%$.

ORDERING INFORMATION

Device	Package	Shipping
2N5038	TO-204	100 Units / Tray
2N5038G	TO-204 (Pb-Free)	

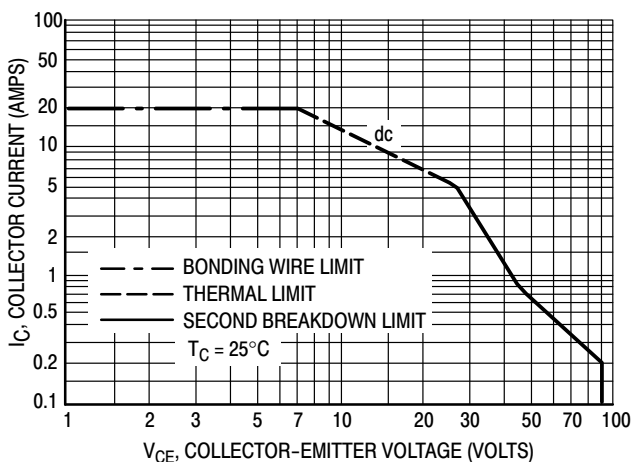


Figure 2. Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

Second breakdown pulse limits are valid for duty cycles to 10%. At high case temperatures, thermal limitations may reduce the power that can be handled to values less than the limitations imposed by second breakdown.

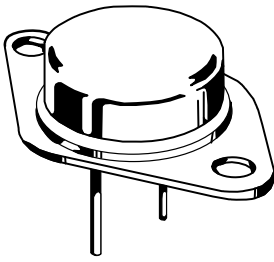
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor

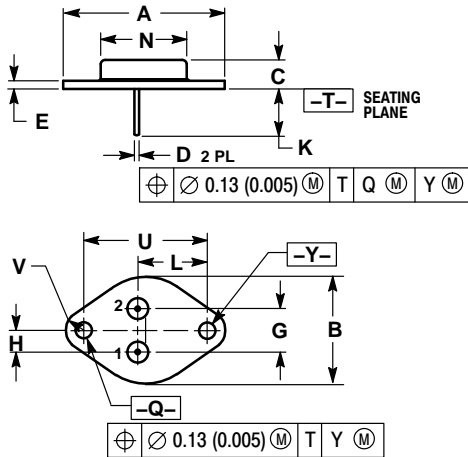


TO-204 (TO-3)
CASE 1-07
ISSUE Z

DATE 05/18/1988



SCALE 1:1



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF	---	39.37 REF	---
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC	---	10.92 BSC	---
H	0.215 BSC	---	5.46 BSC	---
K	0.440	0.480	11.18	12.19
L	---	0.665 BSC	---	16.89 BSC
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC	---	30.15 BSC	---
V	0.131	0.188	3.33	4.77

- | | | | | |
|--------------------------------------------------------------------|--------------------------------------------------------------------|-------------------------------------------------------------------------|-----------------------------------------------------------------------|-------------------------------------------------------------------------------|
| <p>STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR</p> | <p>STYLE 2:
PIN 1. BASE
2. COLLECTOR
CASE: EMITTER</p> | <p>STYLE 3:
PIN 1. GATE
2. SOURCE
CASE: DRAIN</p> | <p>STYLE 4:
PIN 1. GROUND
2. INPUT
CASE: OUTPUT</p> | <p>STYLE 5:
PIN 1. CATHODE
2. EXTERNAL TRIP/DELAY
CASE: ANODE</p> |
| <p>STYLE 6:
PIN 1. GATE
2. EMITTER
CASE: COLLECTOR</p> | <p>STYLE 7:
PIN 1. ANODE
2. OPEN
CASE: CATHODE</p> | <p>STYLE 8:
PIN 1. CATHODE #1
2. CATHODE #2
CASE: ANODE</p> | <p>STYLE 9:
PIN 1. ANODE #1
2. ANODE #2
CASE: CATHODE</p> | |

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